











SN74LVC1G00

SCES212AB - APRIL 1999-REVISED APRIL 2014

SN74LVC1G00 Single 2-Input Positive-NAND Gate

Features

- Available in the Ultra Small 0.64-mm² Package (DPW) With 0.5-mm Pitch
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Provides Down Translation to V_{CC}
- Max t_{od} of 3.8 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Live Insertion, Partial-Power-Down Mode, and Back Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 1000-V Charged-Device Model (C101)

2 Applications

- **AV Receiver**
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- MP3 Player/Recorder (Portable Audio)
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive (SSD): Client and Enterprise
- TV: LCD/Digital and High-Definition (HDTV)
- Tablet: Enterprise
- Video Analytics: Server
- Wireless Headset, Keyboard, and Mouse

Simplified Schematic



3 Description

This single 2-input positive-NAND gate is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G00 performs the Boolean function $Y = A \times B$ or Y = A + B in positive logic.

The CMOS device has high output drive while maintaining low static power dissipation over a broad V_{CC} operating range.

The SN74LVC1G00 is available in a variety of packages, including the ultra-small DPW package with a body size of 0.8 mm × 0.8 mm.

Device Information⁽¹⁾

| DEVICE NAME | PACKAGE | BODY SIZE | | |
|-------------|------------|-----------------|--|--|
| | SOT-23 (5) | 2.9mm × 1.6mm | | |
| | SC70 (5) | 2.0mm × 1.25mm | | |
| SN74LVC1G00 | X2SON (4) | 0.8mm × 0.8mm | | |
| | SON (6) | 1.45mm × 1.0mm | | |
| | DSBGA (5) | 1.41mm × 0.91mm | | |

(1) For all available packages, see the orderable addendum at the end of the datasheet.



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5 Revision History

| CI | hanges from Revision AA (March 2014) to Revision AB | Page |
|----|---|------|
| • | Added Pin Functions table. | |
| • | Updated Handling Ratings table. | 3 |
| | Added Thermal Information table. | |
| • | Added Typical Characteristics. | (|
| • | Added Detailed Description section. | |
| • | Added Application and Implementation section. | 10 |
| • | Added Power Supply Recommendations section. | 11 |
| • | Added Layout section. | 1′ |

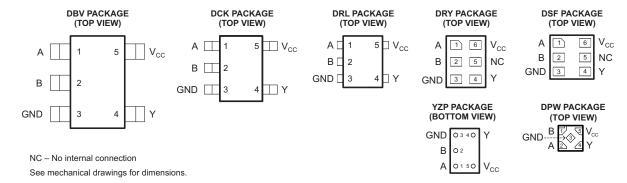
| C | Changes from Revision Z (November 2014) to Revision AA | | | |
|---|--|---|--|--|
| • | Added Applications section. | 1 | | |
| • | Added Device Information table. | 1 | | |
| • | Added T _{stg} to Handling Ratings table. | 3 | | |

| Changes from Revision Y (September 2013) to Revision Z | | | | |
|--|----------------------------|--|--|--|
| • | Changed document Features. | | | |

| Changes from Revision X (November 2012) to Revision Y | | | | |
|---|--|---|--|--|
| • | Extended operating temperature from 85°C to 125°C. | 4 | | |



6 Pin Configuration and Functions



Pin Functions

| ı | | _ | | | |
|---|-----------------|-----------------------|----------|-----|---------------|
| | | PI | N | | |
| | NAME | DBV, DCK, DRL, YZP | DRY, DSF | DPW | DESCRIPTION |
| | Α | A 1 1 2 | | 2 | Input |
| | В | 2 | 2 | 1 | Input |
| | GND | 3 | 3 | 3 | Ground |
| | Υ | 4 | 4 | 4 | Output |
| | V _{CC} | 5 | 6 | 5 | Power pin |
| | NC | | 5 | | Not connected |

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-----------------|--|----------------------|------|-----------------------|------|
| V_{CC} | Supply voltage range | Supply voltage range | | | V |
| V_{I} | Input voltage range | | -0.5 | 6.5 | V |
| Vo | Voltage range applied to any output in the high-impedance or power-off state (2) | | -0.5 | 6.5 | V |
| Vo | Voltage range applied to any output in the high or low state (2)(3) | | -0.5 | V _{CC} + 0.5 | V |
| I _{IK} | Input clamp current | V _I < 0 | | – 50 | mA |
| lok | Output clamp current | V _O < 0 | | – 50 | mA |
| Io | Continuous output current | | | ±50 | mA |
| | Continuous current through V _{CC} or GND | | | ±100 | mA |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

| | | | MIN | MAX | UNIT |
|--------------------|--------------------------|---|-----|------|------|
| T _{stg} | Storage temperature rang | Storage temperature range | | | |
| V _(ESD) | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾ | 0 | 2000 | V |
| | | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2) | 0 | 1000 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.3 Recommended Operating Conditions⁽¹⁾

| | | | MIN | MAX | UNIT | |
|-----------------|------------------------------------|--|------------------------|------------------------|------|--|
| \ / | Committee | Operating | 1.65 | 5.5 | V | |
| V_{CC} | Supply voltage | Data retention only | 1.5 | | V | |
| | | V _{CC} = 1.65 V to 1.95 V | 0.65 × V _{CC} | | | |
| V | I Park Javas Computer at the ma | V _{CC} = 2.3 V to 2.7 V | 1.7 | | | |
| V_{IH} | High-level input voltage | V _{CC} = 3 V to 3.6 V | 2 | | V | |
| | | V _{CC} = 4.5 V to 5.5 V | 0.7 × V _{CC} | | | |
| | | V _{CC} = 1.65 V to 1.95 V | | 0.35 × V _{CC} | | |
| V_{IL} | | V _{CC} = 2.3 V to 2.7 V | | 0.7 | | |
| | Low-level input voltage | V _{CC} = 3 V to 3.6 V | | 0.8 | V | |
| | | V _{CC} = 4.5 V to 5.5 V | 0.3 × V _{CC} | | | |
| VI | Input voltage | | 0 | 5.5 | V | |
| Vo | Output voltage | | 0 | V _{CC} | V | |
| | High-level output current | V _{CC} = 1.65 V | | -4 | | |
| | | V _{CC} = 2.3 V | | -8 | | |
| I _{OH} | | V 0V | | -16 | mA | |
| | | V _{CC} = 3 V | | -24 | | |
| | | V _{CC} = 4.5 V | | -32 | | |
| | | V _{CC} = 1.65 V | | 4 | | |
| | | V _{CC} = 2.3 V | | 8 | | |
| l _{OL} | Low-level output current | V 6V | | 16 | mA | |
| | | V _{CC} = 3 V | | 24 | | |
| | | V _{CC} = 4.5 V | | 32 | | |
| | | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$ | | | ns/V | |
| Δt/Δν | Input transition rise or fall rate | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | | | | |
| | • | $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ | | | | |
| T _A | Operating free-air temperature | , | -40 | 125 | °C | |

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

7.4 Thermal Information

| | nonna miorination | | | | | | | |
|----------------------|--|--------|-------------|--------|--------|--------|--------|-------|
| | | | SN74LVC1G00 | | | | | |
| | THERMAL METRIC (1) | DBV | DCK | DRL | DRY | YZP | DPW | UNIT |
| | | 5 PINS | 5 PINS | 5 PINS | 6 PINS | 5 PINS | 4 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 229 | 278 | 243 | 439 | 130 | 340 | |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 164 | 93 | 78 | 277 | 54 | 215 | |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 62 | 65 | 78 | 271 | 51 | 294 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 44 | 2 | 10 | 84 | 1 | 41 | *C/VV |
| Ψ_{JB} | Junction-to-board characterization parameter | 62 | 64 | 77 | 271 | 50 | 294 | |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | _ | - | _ | - | _ | 250 | |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS V _C | Vcc | −40°C to 85°C | | | RECOMMENDED -40°C to 125°C | | | UNIT | |
|------------------|---------------|---|-----------------|-----------------------|--------------------|------|-------------------------------|--------------------|------|------|--|
| | | | | MIN | TYP ⁽¹⁾ | MAX | MIN | TYP ⁽¹⁾ | MAX | | |
| | | I _{OH} = -100 μA | 1.65 V to 5.5 V | V _{CC} - 0.1 | | | V _{CC} - 0.1 | | | | |
| | | $I_{OH} = -4 \text{ mA}$ | 1.65 V | 1.2 | | | 1.2 | | | | |
| ., | | I _{OH} = -8 mA | 2.3 V | 1.9 | | | 1.9 | | | \ / | |
| V _{OH} | | I _{OH} = -16 mA | 3 V | 2.4 | | | 2.4 | | | V | |
| | | I _{OH} = -24 mA | 3 V | 2.3 | | | 2.3 | | | | |
| | | I _{OH} = -32 mA | 4.5 V | 3.8 | | | 3.8 | | | | |
| | | I _{OL} = 100 μA | 1.65 V to 5.5 V | | | 0.1 | | | 0.1 | | |
| | | I _{OL} = 4 mA | 1.65 V | | | 0.45 | | | 0.45 | V | |
| \/ | | I _{OL} = 8 mA | 2.3 V | | | 0.3 | | | 0.3 | | |
| V _{OL} | | I _{OL} = 16 mA | 3 V | | | 0.4 | | | 0.4 | V | |
| | | I _{OL} = 24 mA | 3 V | | | 0.55 | | | 0.55 | | |
| | | I _{OL} = 32 mA | 4.5 V | | | 0.55 | | | 0.55 | | |
| I ₁ | A or B inputs | V _I = 5.5 V or GND | 0 to 5.5 V | | | ±5 | | | ±5 | μA | |
| I _{off} | | V_I or $V_O = 5.5 \text{ V}$ | 0 | | | ±10 | | | ±10 | μΑ | |
| I _{CC} | | V _I = 5.5 V or GND I _O = 0 | 1.65 V to 5.5 V | | | 10 | | | 10 | μA | |
| ΔI _{CC} | | One input at $V_{CC} = 0.6 \text{ V}$, Other inputs at V_{CC} or GND | 3 V to 5.5 V | | | 500 | | | 500 | μA | |
| Ci | | V _I = V _{CC} or GND | 3.3 V | | 4 | | | 4 | | pF | |

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

7.6 Switching Characteristics, $C_L = 15 pF$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

| | | | | | | –40°C | to 85°C | | | | |
|------------------------|--------|----------------|-------------------------------------|-----|------------------------------------|-------|------------------------------------|-----|----------------------------------|-----|------|
| PARAMETER FROM (INPUT) | | TO (OUTPUT) | V _{CC} = 1.8 V ± 0.15 V | | V _{CC} = 2.5 V ± 0.2 V | | V _{CC} = 3.3 V ± 0.3 V | | V _{CC} = 5 V ± 0.5 V | | UNIT |
| | | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{pd} | A or B | Y | 2.2 | 7.2 | 0.9 | 4.4 | 0.8 | 3.8 | 0.8 | 3.4 | ns |

7.7 Switching Characteristics, -40°C to 85°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 4)

| PARAMETER FROM (INPUT) | | | −40°C to 85°C | | | | | | | | |
|------------------------|--------|----------------|-------------------------------------|-----|------------------------------------|-----|------------------------------------|-----|----------------------------------|-----|------|
| | | TO (OUTPUT) | V _{CC} = 1.8 V ± 0.15 V | | V _{CC} = 2.5 V ± 0.2 V | | V _{CC} = 3.3 V ± 0.3 V | | V _{CC} = 5 V ± 0.5 V | | UNIT |
| | | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{pd} | A or B | Υ | 3.1 | 9 | 1.3 | 5.5 | 1 | 4.7 | 1 | 4 | ns |

7.8 Switching Characteristics, -40°C to 125°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 4)

| | | | RECOMMENDED -40°C to 125°C | | | | | | | | |
|-----------------|-----------------|----------------|-------------------------------------|-----|------------------------------------|-----|------------------------------------|-----|----------------------------------|-----|------|
| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = 1.8 V ± 0.15 V | | V _{CC} = 2.5 V ± 0.2 V | | V _{CC} = 3.3 V ± 0.3 V | | V _{CC} = 5 V ± 0.5 V | | UNIT |
| | | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{pd} | A or B | Υ | 3.1 | 9.7 | 1.3 | 5.8 | 1 | 5 | 1 | 4.3 | ns |
| t _{pd} | Α | Υ | 2 | 6.4 | 1 | 4.2 | 0.7 | 3.3 | 0.7 | 3.1 | ns |

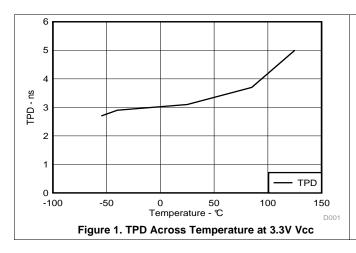


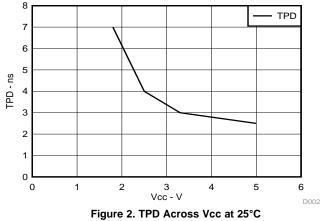
7.9 Operating Characteristics

 $T_A = 25^{\circ}C$

| | PARAMETER | TEST CONDITIONS | V _{CC} = 1.8 V TYP | V _{CC} = 2.5 V TYP | V _{CC} = 3.3 V TYP | V _{CC} = 5 V TYP | UNIT |
|-----------------|-------------------------------|--------------------|--------------------------------|--------------------------------|--------------------------------|------------------------------|------|
| C _{pd} | Power dissipation capacitance | f = 10 MHz | 22 | 22 | 23 | 25 | pF |

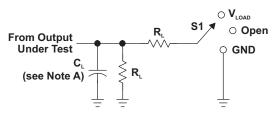
7.10 Typical Characteristics







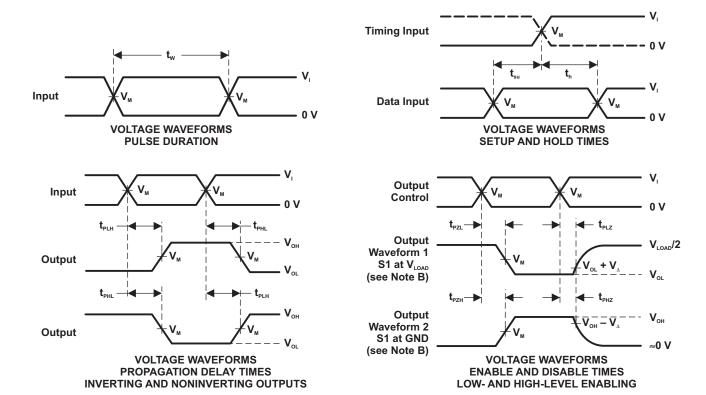
8 Parameter Measurement Information



| TEST | S1 |
|------------------------------------|-------------------|
| t _{PLH} /t _{PHL} | Open |
| t _{PLZ} /t _{PZL} | V _{LOAD} |
| t _{PHZ} /t _{PZH} | GND |

LOAD CIRCUIT

| ., | INF | INPUTS | | ., | | - | ., |
|-----------------|-----------------|---------|--------------------|---------------------|----------------|----------------------------|----------------|
| V _{cc} | V _i | t,/t, | V _M | V _{LOAD} | C _L | $R_{\scriptscriptstyle L}$ | V _A |
| 1.8 V ± 0.15 V | V _{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 15 pF | 1 M Ω | 0.15 V |
| 2.5 V ± 0.2 V | V_{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 15 pF | 1 M Ω | 0.15 V |
| 3.3 V ± 0.3 V | 3 V | ≤2.5 ns | 1.5 V | 6 V | 15 pF | 1 M Ω | 0.3 V |
| 5 V ± 0.5 V | V_{cc} | ≤2.5 ns | V _{cc} /2 | 2 × V _{cc} | 15 pF | 1 M Ω | 0.3 V |



NOTES: A. C_L includes probe and jig capacitance.

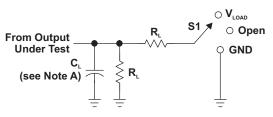
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{o} = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. $t_{\mbox{\tiny PLZ}}$ and $t_{\mbox{\tiny PHZ}}$ are the same as $t_{\mbox{\tiny dis}}.$
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

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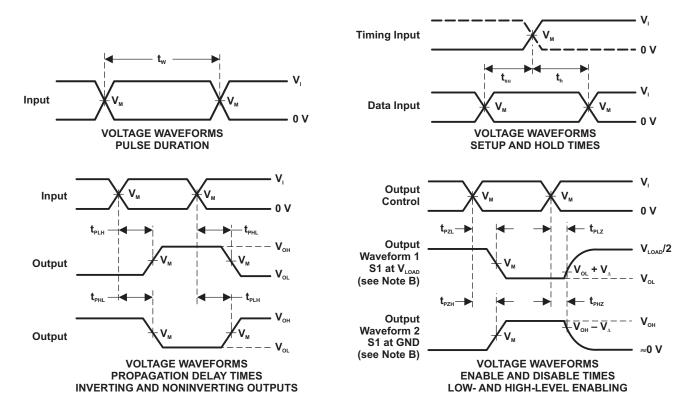
Parameter Measurement Information (continued)



| TEST | S1 |
|------------------------------------|-------------------|
| t _{PLH} /t _{PHL} | Open |
| t _{PLZ} /t _{PZL} | V _{LOAD} |
| t _{PHZ} /t _{PZH} | GND |

LOAD CIRCUIT

| ., | INI | PUTS | | ., | | | ., |
|-----------------------------------|-----------------|---------|--------------------|--------------------------|----------------|----------------|----------------|
| V _{cc} | V, | t,/t, | V _M | V _{LOAD} | C _∟ | R _⊾ | V _A |
| 1.8 V ± 0.15 V | V _{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 30 pF | 1 k Ω | 0.15 V |
| $2.5~V~\pm~0.2~V$ | V _{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 30 pF | 500 Ω | 0.15 V |
| $3.3 \text{ V} \pm 0.3 \text{ V}$ | 3 V | ≤2.5 ns | 1.5 V | 6 V | 50 pF | 500 Ω | 0.3 V |
| 5 V ± 0.5 V | V _{cc} | ≤2.5 ns | V _{cc} /2 | 2 × V _{cc} | 50 pF | 500 Ω | 0.3 V |



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \,\Omega$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and \dot{t}_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. $t_{\text{PLH}}^{\text{F2L}}$ and $t_{\text{PHL}}^{\text{F2L}}$ are the same as $t_{\text{pd}}^{\text{eff}}$
- H. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

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9 Detailed Description

9.1 Overview

The <u>SN74LVC1G00</u> device contains one 2-input positive-NAND gate and performs the Boolean function $Y = \overline{A} \times \overline{B}$ or $Y = \overline{A} + \overline{B}$. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The DPW package technology is a major breakthrough in IC packaging. Its tiny 0.64 mm square footprint saves significant board space over other package options while still retaining the traditional manufacturing friendly lead pitch of 0.5 mm.

9.2 Functional Block Diagram



9.3 Feature Description

- · Wide operating voltage range.
 - Operates from 1.65 V to 5.5 V.
- · Allows down voltage translation.
- Inputs accept voltages to 5.5 V.
- I_{off} feature allows voltages on the inputs and outputs, when V_{CC} is 0 V.

9.4 Device Functional Modes

Function Table

| INPL | ITS | OUTPUT |
|------|-----|--------|
| Α | В | Y |
| Н | Н | L |
| L | X | Н |
| X | L | Н |

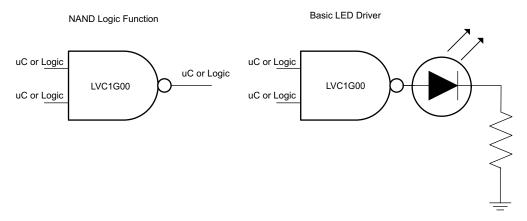


10 Application and Implementation

10.1 Application Information

The SN74LVC1G00 is a high drive CMOS device that can be used for implementing NAND logic with a high output drive, such as an LED application. It can produce 24 mA of drive current at 3.3 V making it Ideal for driving multiple outputs and good for high speed applications up to 100 MHz. The inputs are 5.5 V tolerant allowing it to translate down to $V_{\rm CC}$.

10.2 Typical Application



10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs. See (Δt/ΔV) in Recommended Operating Conditions table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as (V_I max) in the Recommended Operating Conditions table at any valid V_{CC}.

2. Recommend Output Conditions

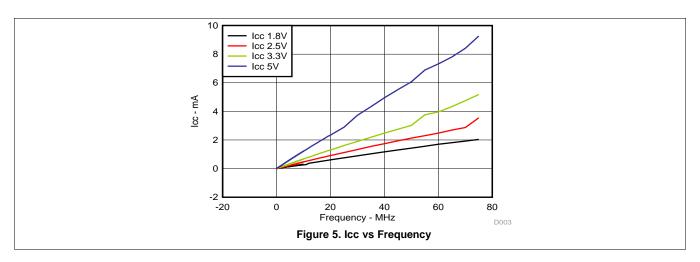
- Load currents should not exceed (I_O max) per output and should not exceed total current (continuous current through V_{CC} or GND) for the part. These limits are located in the Absolute Maximum Ratings table
- Outputs should not be pulled above V_{CC}.

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Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the Recommended Operating Conditions table.

Each Vcc pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply a 0.1-µF capacitor is recommended and if there are multiple Vcc pins then a 0.01-µF or 0.022-µF capacitor is recommended for each power pin. It is ok to parallel multiple bypass caps to reject different frequencies of noise. 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

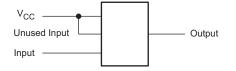
12 Layout

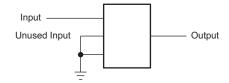
12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to Gnd or Vcc whichever make more sense or is more convenient.

12.2 Layout Example

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13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LVC1G00

John Documentation Feedback





4-May-2017

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead/Ball Finish (6) | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|-------------------|--------|--------------|--------------------|------|----------------|----------------------------|----------------------|--------------------|--------------|---|---------|
| SN74LVC1G00DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU CU SN | Level-1-260C-UNLIM | -40 to 125 | (C005 ~ C00F ~ C00K ~ C00R) (C00H ~ C00P ~ C00S) | Samples |
| SN74LVC1G00DBVRE4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C00F | Samples |
| SN74LVC1G00DBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C00F | Samples |
| SN74LVC1G00DBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU CU SN | Level-1-260C-UNLIM | -40 to 125 | (C005 ~ C00F ~ C00K ~ C00R) (C00H ~ C00P ~ C00S) | Samples |
| SN74LVC1G00DBVTE4 | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C00F | Samples |
| SN74LVC1G00DBVTG4 | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C00F | Samples |
| SN74LVC1G00DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CA5 ~ CAF ~ CAK ~ CAR) (CAH ~ CAP ~ CAS) | Samples |
| SN74LVC1G00DCKRE4 | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CA5 ~ CAF ~ CAK ~ CAR) (CAH ~ CAP ~ CAS) | Samples |
| SN74LVC1G00DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CA5 ~ CAF ~ CAK ~ CAR) (CAH ~ CAP ~ CAS) | Samples |
| SN74LVC1G00DCKT | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CA5 ~ CAF ~ CAK ~ CAR) (CAH ~ CAP ~ CAS) | Samples |
| SN74LVC1G00DCKTE4 | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CA5 ~ CAF ~ CAK ~ CAR) (CAH ~ CAP ~ CAS) | Samples |
| SN74LVC1G00DCKTG4 | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CA5 ~ CAF ~ CAK ~ CAR) (CAH ~ CAP ~ CAS) | Samples |
| SN74LVC1G00DPWR | ACTIVE | X2SON | DPW | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | H4 | Samples |



PACKAGE OPTION ADDENDUM

4-May-2017

| Orderable Device | Status | Package Type | _ | | Package | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|-------------------|--------|--------------|---------|---|---------|----------------------------|----------------------------|--------------------|--------------|-----------------------|---------|
| | (1) | | Drawing | | Qty | (2) | (6) | (3) | | (4/5) | |
| SN74LVC1G00DRLR | ACTIVE | SOT-5X3 | DRL | 5 | 4000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CA7 ~ CAR) | Samples |
| SN74LVC1G00DRLRG4 | ACTIVE | SOT-5X3 | DRL | 5 | 4000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CA7 ~ CAR) | Samples |
| SN74LVC1G00DRY2 | ACTIVE | SON | DRY | 6 | 5000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CA | Samples |
| SN74LVC1G00DRYR | ACTIVE | SON | DRY | 6 | 5000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CA | Samples |
| SN74LVC1G00DSF2 | ACTIVE | SON | DSF | 6 | 5000 | Green (RoHS & no Sb/Br) | CU NIPDAU CU NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | CA | Samples |
| SN74LVC1G00DSFR | ACTIVE | SON | DSF | 6 | 5000 | Green (RoHS & no Sb/Br) | CU NIPDAU CU NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | CA | Samples |
| SN74LVC1G00YZPR | ACTIVE | DSBGA | YZP | 5 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | (CA7 ~ CAN) | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

4-May-2017

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC1G00:

Enhanced Product: SN74LVC1G00-EP

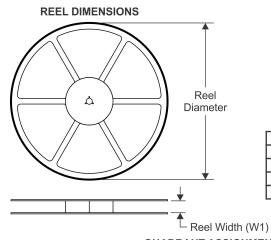
NOTE: Qualified Version Definitions:

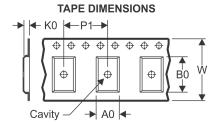
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Aug-2017

TAPE AND REEL INFORMATION





| | Dimension designed to accommodate the component width |
|----|---|
| | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



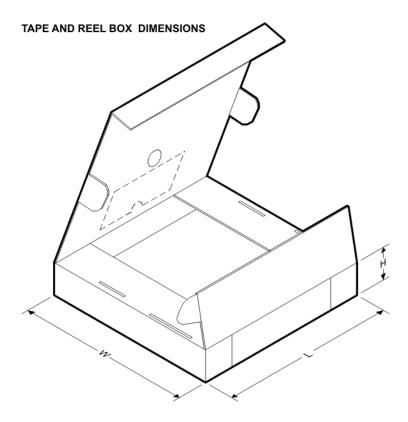
*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74LVC1G00DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DBVR | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.2 | 3.3 | 3.23 | 1.55 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DBVR | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DBVRG4 | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DBVT | SOT-23 | DBV | 5 | 250 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DBVT | SOT-23 | DBV | 5 | 250 | 178.0 | 9.2 | 3.3 | 3.23 | 1.55 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DBVTG4 | SOT-23 | DBV | 5 | 250 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.2 | 2.4 | 2.4 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DCKT | SC70 | DCK | 5 | 250 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DCKT | SC70 | DCK | 5 | 250 | 178.0 | 9.2 | 2.4 | 2.4 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DCKT | SC70 | DCK | 5 | 250 | 180.0 | 9.2 | 2.3 | 2.55 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DPWR | X2SON | DPW | 5 | 3000 | 178.0 | 8.4 | 0.91 | 0.91 | 0.5 | 2.0 | 8.0 | Q3 |
| SN74LVC1G00DRLR | SOT-5X3 | DRL | 5 | 4000 | 180.0 | 9.5 | 1.78 | 1.78 | 0.69 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DRLR | SOT-5X3 | DRL | 5 | 4000 | 180.0 | 8.4 | 1.98 | 1.78 | 0.69 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DRY2 | SON | DRY | 6 | 5000 | 180.0 | 9.5 | 1.6 | 1.15 | 0.75 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DRY2 | SON | DRY | 6 | 5000 | 180.0 | 8.4 | 1.65 | 1.2 | 0.7 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DRYR | SON | DRY | 6 | 5000 | 180.0 | 9.5 | 1.15 | 1.6 | 0.75 | 4.0 | 8.0 | Q1 |
| SN74LVC1G00DSF2 | SON | DSF | 6 | 5000 | 180.0 | 8.4 | 1.16 | 1.16 | 0.63 | 4.0 | 8.0 | Q3 |

PACKAGE MATERIALS INFORMATION

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| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74LVC1G00DSF2 | SON | DSF | 6 | 5000 | 180.0 | 9.5 | 1.16 | 1.16 | 0.5 | 4.0 | 8.0 | Q3 |
| SN74LVC1G00DSFR | SON | DSF | 6 | 5000 | 180.0 | 9.5 | 1.16 | 1.16 | 0.5 | 4.0 | 8.0 | Q2 |
| SN74LVC1G00YZPR | DSBGA | YZP | 5 | 3000 | 178.0 | 9.2 | 1.02 | 1.52 | 0.63 | 4.0 | 8.0 | Q1 |



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74LVC1G00DBVR | SOT-23 | DBV | 5 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74LVC1G00DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DBVRG4 | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DBVTG4 | SOT-23 | DBV | 5 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DCKT | SC70 | DCK | 5 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DCKT | SC70 | DCK | 5 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G00DCKT | SC70 | DCK | 5 | 250 | 205.0 | 200.0 | 33.0 |
| SN74LVC1G00DPWR | X2SON | DPW | 5 | 3000 | 205.0 | 200.0 | 33.0 |
| SN74LVC1G00DRLR | SOT-5X3 | DRL | 5 | 4000 | 184.0 | 184.0 | 19.0 |
| SN74LVC1G00DRLR | SOT-5X3 | DRL | 5 | 4000 | 202.0 | 201.0 | 28.0 |



PACKAGE MATERIALS INFORMATION

www.ti.com 3-Aug-2017

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74LVC1G00DRY2 | SON | DRY | 6 | 5000 | 184.0 | 184.0 | 19.0 |
| SN74LVC1G00DRY2 | SON | DRY | 6 | 5000 | 202.0 | 201.0 | 28.0 |
| SN74LVC1G00DRYR | SON | DRY | 6 | 5000 | 184.0 | 184.0 | 19.0 |
| SN74LVC1G00DSF2 | SON | DSF | 6 | 5000 | 202.0 | 201.0 | 28.0 |
| SN74LVC1G00DSF2 | SON | DSF | 6 | 5000 | 184.0 | 184.0 | 19.0 |
| SN74LVC1G00DSFR | SON | DSF | 6 | 5000 | 184.0 | 184.0 | 19.0 |
| SN74LVC1G00YZPR | DSBGA | YZP | 5 | 3000 | 220.0 | 220.0 | 35.0 |

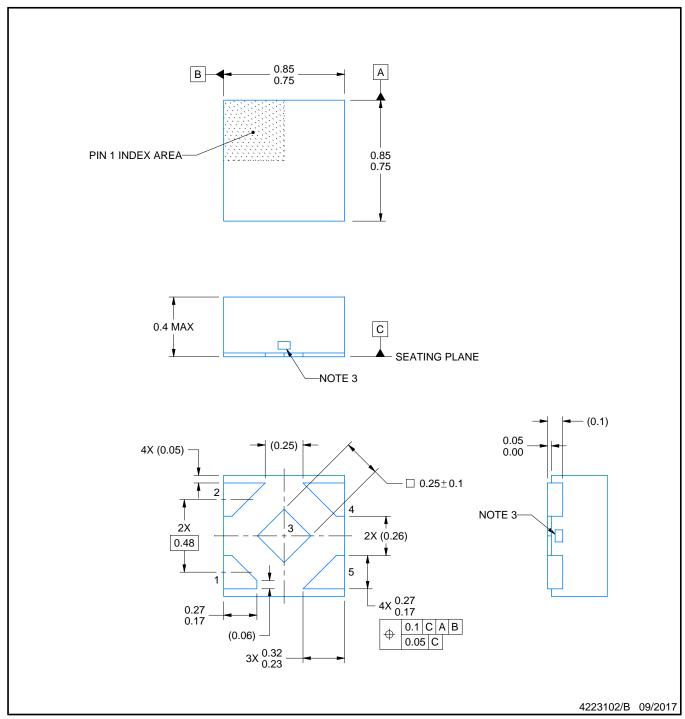


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4211218-3/D



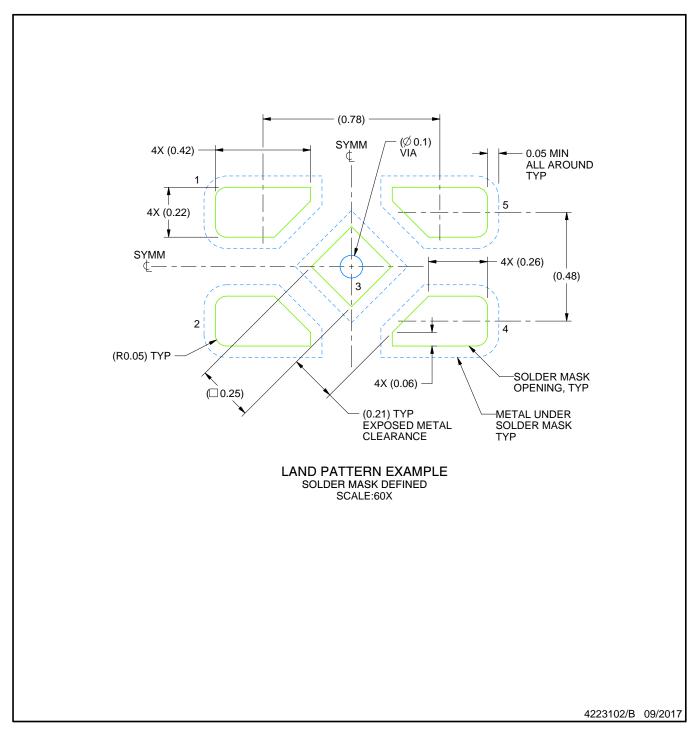




- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.

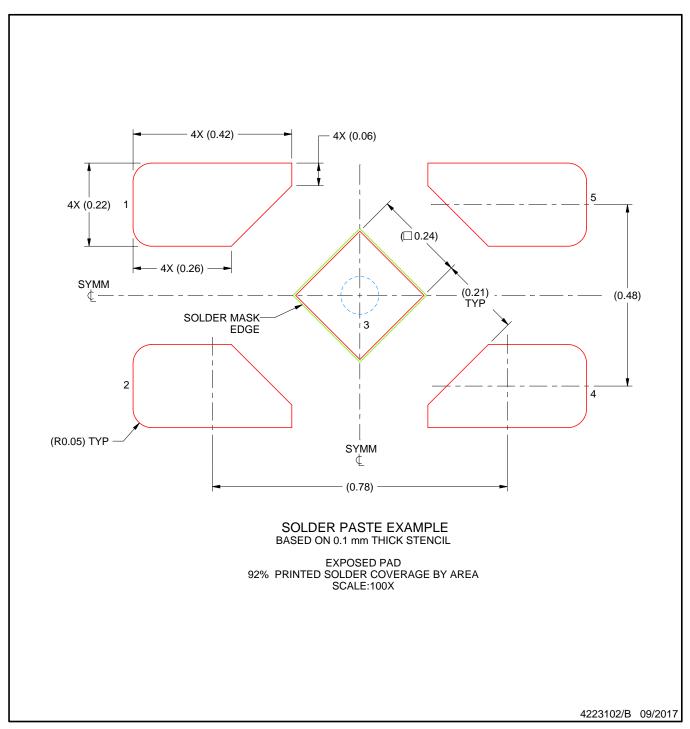




NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).





NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





DIE SIZE BALL GRID ARRAY



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration MO-287, variation X2AAF.







- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.









- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.





NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).





NOTES: (continued)

Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4073253/P





SMALL OUTLINE TRANSISTOR



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC MO-178.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

 Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



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